Octal Buffer/Line Driver with 3-State Outputs

The MC74AC240/74ACT240 is an octal buffer and line driver designed to be employed as a memory address driver, clock driver and bus oriented transmitter or receiver which provides improved PC board density.

Features

- 3-State Outputs Drive Bus Lines or Buffer Memory Address Registers
- Outputs Source/Sink 24 mA
- 'ACT240 Has TTL Compatible Inputs
- These are Pb–Free Devices

TRUTH TABLE

| Inputs | | Outputs |
|-------------------|---|-----------------------|
| \overline{OE}_1 | D | (Pins 12, 14, 16, 18) |
| L | L | Н |
| L | н | L |
| Н | Х | Z |

NOTE: H = HIGH Voltage Level L = LOW Voltage Level X = Immaterial

Z = High Impedance

TRUTH TABLE

| Inputs | | Outputs |
|--------------------------|---|-------------------|
| $\overline{\text{OE}}_2$ | D | (Pins 3, 5, 7, 9) |
| L | L | Н |
| L | н | L |
| Н | Х | Z |

NOTE: H = HIGH Voltage Level L = LOW Voltage Level

X = Immaterial

Z = High Impedance



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SOIC-20W DW SUFFIX CASE 751D



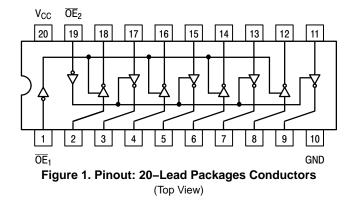
TSSOP-20 DT SUFFIX CASE 948E

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

DEVICE MARKING INFORMATION

See general marking information in the device marking section on page 7 of this data sheet.



MAXIMUM RATINGS

| Symbol | Parameter | | Value | Unit |
|----------------------|-------------------------------------------------------|-------------------------------------------------------------------------|------------------------------|------|
| V _{CC} | DC Supply Voltage (Referenced to GND) | | -0.5 to +7.0 | V |
| V _{IN} | DC Input Voltage (Referenced to GND) | | –0.5 to V _{CC} +0.5 | V |
| V _{OUT} | DC Output Voltage (Referenced to GND) (Note 1) | | –0.5 to V _{CC} +0.5 | V |
| Ι _{ΙΚ} | DC Input Diode Current | | ±20 | mA |
| I _{OK} | DC Output Diode Current | | ±50 | mA |
| I _{OUT} | DC Output Sink/Source Current | | ±50 | mA |
| I _{CC} | DC Supply Current, per Output Pin | | ±50 | mA |
| I _{GND} | DC Ground Current, per Output Pin | | ±100 | mA |
| T _{STG} | Storage Temperature Range | | -65 to +150 | °C |
| ΤL | Lead temperature, 1 mm from Case for 10 Seconds | | 260 | °C |
| TJ | Junction Temperature Under Bias | | 140 | °C |
| θ_{JA} | Thermal Resistance (Note 2) | SOIC TSSOP | 65.8 110.7 | °C/W |
| MSL | Moisture Sensitivity | | Level 1 | |
| F _R | Flammability Rating Oxyg | en Index: 30% – 35% | UL 94 V–0 @ 0.125 in | |
| V _{ESD} | Ma | a Body Model (Note 3) achine Model (Note 4) Device Model (Note 5) | > 2000 > 200 > 1000 | V |
| I _{Latchup} | Latchup Performance Above V _{CC} and Below 0 | GND at 85°C (Note 6) | ±100 | mA |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

I₀ absolute maximum rating must be observed.
 The package thermal impedance is calculated in accordance with JESD 51–7.
 Tested to EIA/JESD22–A114–A.

4. Tested to EIA/JESD22-A115-A.

Tested to JESD22-C101-A. 5.

6. Tested to EIA/JESD78.

RECOMMENDED OPERATING CONDITIONS

| Symbol | Parameter | | Min | Тур | Max | Unit |
|------------------------------------|-------------------------------------------------------------------------------------------------------------------|-------------------------|-----|-----|-----------------|------|
| | | ′AC | 2.0 | 5.0 | 6.0 | Ň |
| V _{CC} | Supply Voltage | ΆCΤ | 4.5 | 5.0 | 5.5 | V |
| V _{IN} , V _{OUT} | DC Input Voltage, Output Voltage (Ref. to GND) | - | 0 | - | V _{CC} | V |
| | | V _{CC} @ 3.0 V | - | 150 | - | |
| t _r , t _f | Input Rise and Fall Time (Note 7) AC Devices except Schmitt Inputs | V _{CC} @ 4.5 V | - | 40 | - | ns/V |
| | | V _{CC} @ 5.5 V | - | 25 | - | |
| | Input Rise and Fall Time (Note 8)V _{CC} @ 4.5 V'ACT Devices except Schmitt InputsV _{CC} @ 5.5 V | | - | 10 | - | |
| t _r , t _f | | | - | 8.0 | - | ns/V |
| T _A | Operating Ambient Temperature Range | | | 25 | 85 | °C |
| I _{OH} | Output Current – High | | | - | -24 | mA |
| I _{OL} | Output Current – Low | | | - | 24 | mA |

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

7. V_{IN} from 30% to 70% V_{CC} ; see individual Data Sheets for devices that differ from the typical input rise and fall times. 8. V_{IN} from 0.8 V to 2.0 V; see individual Data Sheets for devices that differ from the typical input rise and fall times.

DC CHARACTERISTICS

| | Parameter | | 74 | AC | 74AC | Unit | Conditions | |
|------------------|--------------------------------------|-------------------|-------------------------|----------------------|--------------------------------|------|------------------------------------------------------------------------------------------------|--|
| Symbol | | V _{CC} | T _A = - | +25°C | T _A =–40°C to +85°C | | | |
| | | (V) | Тур | Gu | aranteed Limits | | | |
| V _{IH} | Minimum High Level Input Voltage | 3.0 4.5 5.5 | 1.5 2.25 2.75 | 2.1 3.15 3.85 | 2.1 3.15 3.85 | V | $V_{OUT} = 0.1 V$ or $V_{CC} - 0.1 V$ | |
| V _{IL} | Maximum Low Level Input Voltage | 3.0 4.5 5.5 | 1.5 2.25 2.75 | 0.9 1.35 1.65 | 0.9 1.35 1.65 | V | $V_{OUT} = 0.1 V$ or $V_{CC} - 0.1 V$ | |
| V _{OH} | Minimum High Level Output Voltage | 3.0 4.5 5.5 | 2.99 4.49 5.49 | 2.9 4.4 5.4 | 2.9 4.4 5.4 | V | l _{OUT} = –50 μA | |
| | | 3.0 4.5 5.5 | | 2.56 3.86 4.86 | 2.46 3.76 4.76 | V | $V_{IN} = V_{IL} \text{ or } V_{IH}$ -12 mA $I_{OH} -24 \text{ mA}$ -24 mA | |
| V _{OL} | Maximum Low Level Output Voltage | 3.0 4.5 5.5 | 0.002 0.001 0.001 | 0.1 0.1 0.1 | 0.1 0.1 0.1 | V | l _{OUT} = 50 μA | |
| | | 3.0 4.5 5.5 | | 0.36 0.36 0.36 | 0.44 0.44 0.44 | V | $V_{IN} = V_{IL} \text{ or } V_{IH}$ 12 mA I_{OL} 24 mA 24 mA | |
| I _{IN} | Maximum Input Leakage Current | 5.5 | - | ±0.1 | ±1.0 | μΑ | $V_I = V_{CC}, GND$ | |
| I _{OZ} | Maximum 3–State Current | 5.5 | - | ±0.5 | ±5.0 | μΑ | $V_{I} (OE) = V_{IL}, V_{IH}$ $V_{I} = V_{CC}, GND$ $V_{O} = V_{CC}, GND$ | |
| I _{OLD} | †Minimum Dynamic | 5.5 | - | - | 75 | mA | V _{OLD} = 1.65 V Ma V _{OHD} = 3.85 V Mir | |
| I _{OHD} | Output Current | 5.5 | _ | - | -75 | mA | | |
| I _{CC} | Maximum Quiescent Supply Current | 5.5 | - | 8.0 | 80 | μΑ | $V_{IN} = V_{CC}$ or GND | |

*All outputs loaded; thresholds on input associated with output under test. †Maximum test duration 2.0 ms, one output loaded at a time.

NOTE: I_{IN} and I_{CC} @ 3.0 V are guaranteed to be less than or equal to the respective limit @ 5.5 V V_{CC}.

| | | | 74AC T _A = +25°C C _L = 50 pF | | | 74AC T _A = -40°C to +85°C C _L = 50 pF | | Unit | Fig. No. |
|------------------|-------------------------------------|--------------------------|----------------------------------------------------------|------------|-------------|----------------------------------------------------------------------|-------------|------|-------------|
| Symbol | Parameter | V _{CC} * (V) | | | | | | | |
| | | | Min | Тур | Max | Min | Max | | |
| t _{PLH} | Propagation Delay Data to Output | 3.3 5.0 | 1.5 1.5 | 6.0 4.5 | 8.0 6.5 | 1.0 1.0 | 9.0 7.0 | ns | 3–5 |
| t _{PHL} | Propagation Delay Data to Output | 3.3 5.0 | 1.5 1.5 | 5.5 4.5 | 8.0 6.0 | 1.0 1.0 | 8.5 6.5 | ns | 3–5 |
| t _{PZH} | Output Enable Time | 3.3 5.0 | 1.5 1.5 | 6.0 5.0 | 10.5 7.0 | 1.0 1.0 | 11.0 8.0 | ns | 3–7 |
| t _{PZL} | Output Enable Time | 3.3 5.0 | 1.5 1.5 | 7.0 5.5 | 10.0 8.0 | 1.0 1.0 | 11.0 8.5 | ns | 3–8 |
| t _{PHZ} | Output Disable Time | 3.3 5.0 | 1.5 1.5 | 7.0 6.5 | 10.0 9.0 | 1.0 1.0 | 10.5 9.5 | ns | 3–7 |
| t _{PLZ} | Output Disable Time | 3.3 5.0 | 1.5 1.5 | 7.5 6.5 | 10.5 9.0 | 1.0 1.0 | 11.5 9.5 | ns | 3–8 |

AC CHARACTERISTICS (For Figures and Waveforms - See AND8277/D at www.onsemi.com)

 * Voltage Range 3.3 V is 3.3 V ± 0.3 V. Voltage Range 5.0 V is 5.0 V ± 0.5 V.

DC CHARACTERISTICS

| | Parameter | | | | 74ACT | Unit | Conditions | |
|------------------|----------------------------------------|------------------------|----------------|--------------|---------------------------------|------|-----------------------------------------------------------------------------|--|
| Symbol | | V _{CC} (V) | | | T _A = −40°C to +85°C | | | |
| | | (V) | Тур | Gu | aranteed Limits | | | |
| V _{IH} | Minimum High Level Input Voltage | 4.5 5.5 | 1.5 1.5 | 2.0 2.0 | 2.0 2.0 | V | $V_{OUT} = 0.1 V$ or $V_{CC} - 0.1 V$ | |
| V _{IL} | Maximum Low Level Input Voltage | 4.5 5.5 | 1.5 1.5 | 0.8 0.8 | 0.8 0.8 | V | $V_{OUT} = 0.1 V$ or $V_{CC} - 0.1 V$ | |
| V _{OH} | Minimum High Level Output Voltage | 4.5 5.5 | 4.49 5.49 | 4.4 5.4 | 4.4 5.4 | V | I _{OUT} = -50 μA | |
| | | 4.5 5.5 | | 3.86 4.86 | 3.76 4.76 | V | $*V_{IN} = V_{IL} \text{ or } V_{IH}$ $I_{OH} -24 \text{ mA}$ -24 mA | |
| V _{OL} | Maximum Low Level Output Voltage | 4.5 5.5 | 0.001 0.001 | 0.1 0.1 | 0.1 0.1 | V | I _{OUT} = 50 μA | |
| | | 4.5 5.5 | | 0.36 0.36 | 0.44 0.44 | V | $*V_{IN} = V_{IL} \text{ or } V_{IH}$ 24 mA I_{OL} 24 mA | |
| I _{IN} | Maximum Input Leakage Current | 5.5 | - | ±0.1 | ±1.0 | μΑ | $V_I = V_{CC}, GND$ | |
| ΔI_{CCT} | Additional Max. I _{CC} /Input | 5.5 | 0.6 | - | 1.5 | mA | $V_{I} = V_{CC} - 2.1 V$ | |
| I _{OZ} | Maximum 3–State Current | 5.5 | _ | ±0.5 | ±5.0 | μΑ | $V_{I} (OE) = V_{IL}, V_{IH}$ $V_{I} = V_{CC}, GND$ $V_{O} = V_{CC}, GND$ | |
| I _{OLD} | †Minimum Dynamic | 5.5 | - | - | 75 | mA | V _{OLD} = 1.65 V Max | |
| I _{OHD} | Output Current | 5.5 | - | - | -75 | mA | V _{OHD} = 3.85 V Min | |
| Icc | Maximum Quiescent Supply Current | 5.5 | _ | 8.0 | 80 | μΑ | $V_{IN} = V_{CC}$ or GND | |

*All outputs loaded; thresholds on input associated with output under test. †Maximum test duration 2.0 ms, one output loaded at a time.

AC CHARACTERISTICS (For Figures and Waveforms – See Section 3 of the ON Semiconductor FACT Data Book, DL138/D)

| | | | 74ACT | | | 74ACT | | | |
|------------------|----------------------------------|-----|--------------------------------------------------|-----|------|--------------------------------------------------------------|------|------|-------------|
| Symbol | Parameter | | T _A = +25°C C _L = 50 pF | | | T _A = -40°C to +85°C C _L = 50 pF | | Unit | Fig. No. |
| | | | Min | Тур | Max | Min | Max | | |
| t _{PLH} | Propagation Delay Data to Output | 5.0 | 1.5 | 6.0 | 8.5 | 1.5 | 9.5 | ns | 3–5 |
| t _{PHL} | Propagation Delay Data to Output | 5.0 | 1.5 | 5.5 | 7.5 | 1.5 | 8.5 | ns | 3–5 |
| t _{PZH} | Output Enable Time | 5.0 | 1.5 | 7.0 | 8.5 | 1.0 | 9.5 | ns | 3–7 |
| t _{PZL} | Output Enable Time | 5.0 | 2.0 | 7.0 | 9.5 | 1.5 | 10.5 | ns | 3–8 |
| t _{PHZ} | Output Disable Time | 5.0 | 2.0 | 8.0 | 9.5 | 2.0 | 10.5 | ns | 3–7 |
| t _{PLZ} | Output Disable Time | 5.0 | 2.5 | 6.5 | 10.0 | 2.0 | 10.5 | ns | 3–8 |

*Voltage Range 5.0 V is 5.0 V ± 0.5 V.

CAPACITANCE

| Symbol | Parameter | Value Typ | Unit | Test Conditions |
|-----------------------------------------------|-------------------|--------------|------|-------------------------|
| C _{IN} | Input Capacitance | 4.5 | pF | $V_{CC} = 5.0 V$ |
| C _{PD} Power Dissipation Capacitance | | 45 | pF | V _{CC} = 5.0 V |

ORDERING INFORMATION

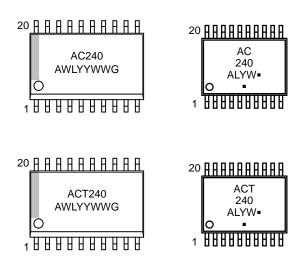
| Device | Package | Shipping [†] |
|-----------------|-----------|-----------------------|
| MC74AC240DWG | | 38 Units / Rail |
| MC74AC240DWR2G | SOIC-20 | 1000 / Tape & Reel |
| MC74ACT240DWG | (Pb-Free) | 38 Units / Rail |
| MC74ACT240DWR2G | | 1000 / Tape & Reel |
| MC74AC240DTR2G | TSSOP-20 | 2500 / Tape & Reel |
| MC74ACT240DTR2G | (Pb-Free) | 2500 / Tape & Reel |

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MARKING DIAGRAMS

SOIC-20W

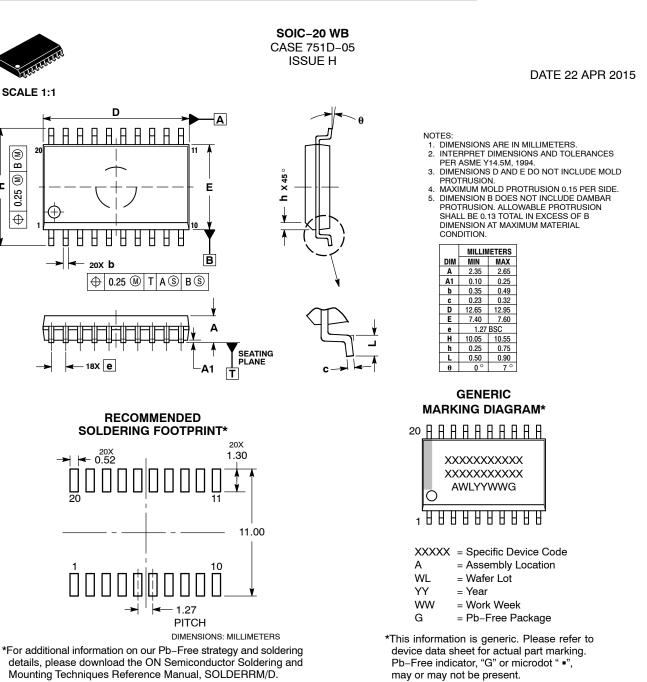
TSSOP-20



| А | = Assembly Location | | | | |
|--------------------------------------------|---------------------|--|--|--|--|
| WL, L | = Wafer Lot | | | | |
| YY, Y | = Year | | | | |
| WW, W | = Work Week | | | | |
| G or ■ | = Pb-Free Package | | | | |
| (Note: Microdot may be in either location) | | | | | |

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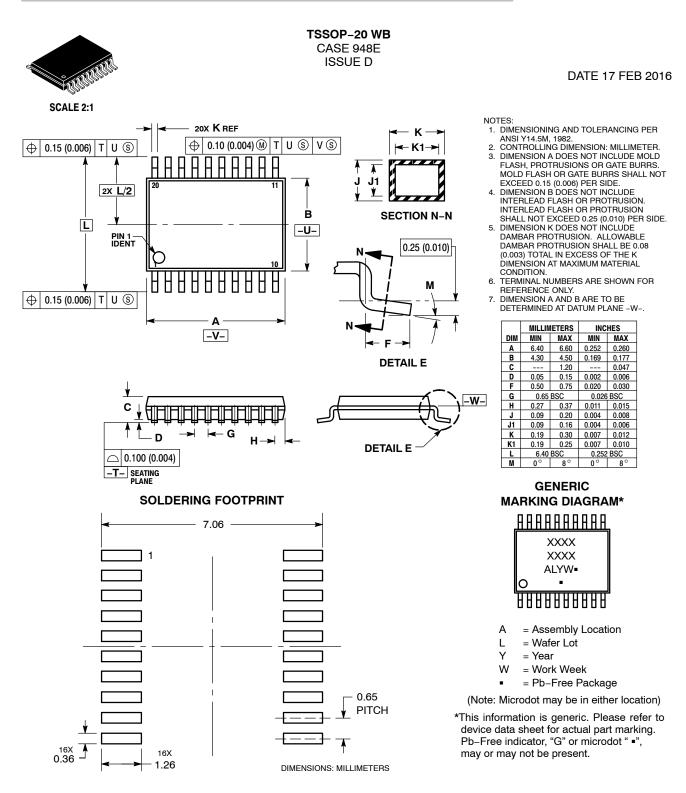


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